NSN 5962-01-339-1361

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Overall Length: 1.490 inches Overall Height: 0.432 inches



View Online at https://aerobasegroup.com/nsn/5962-01-339-1361

Body Length:		
1.490 inches		
Body Width:		
Between 0.500 inc	ches and 0.610 inches	
Body Height:		
Between 0.172 inc	ches and 0.217 inches	
Maximum Power	r Dissipation Rating:	
500.0 milliwatts		
Operating Tempo	urature Range:	
-55.0/+125.0 degr	rees celsius	
Storage Tempura	ature Range:	
-65.0/+150.0 degr	rees celsius	
Features Provide	ed:	
Hermetically seale	ed and burn in and ultraviolet erasable and monolithic and programmed	
Inclosure Materia	al:	
Ceramic		
Inclosure Config	guration:	
Dual-in-line		
Output Logic For	rm:	
Complementary-m	metal oxide-semiconductor logic	
Input Circuit Patt	tern:	
25 input		
Case Outline Sou	urce And Designator:	
D-10 mil-m-38510		
Current Rating P	Per Characteristic:	
50.00 milliampere	es reverse current, dc absolute	
Terminal Surface	e Treatment:	
Solder		
	And Type Per Characteristic:	
5.5 volts power se		
-	g Per Characteristic:	
	arads and 14.00 output picofarads	
Time Rating Per		
200.00 nanosecor		
Memory Device 1	Туре:	
Eprom		
Test Data Docum		
96906-mil-std-883	3 standard (includes industry or association standards, individual manufactureer standards,	etc.).

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Terminal Type Ar	nd Quantity:
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28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0